# **MBR6045WT**

# **SWITCHMODE** <sup>™</sup> **Power Rectifier**

The SWITCHMODE power rectifier employs the use of the Schottky Barrier principle with a Platinum barrier metal.

# **Features**

- Dual Diode Construction; Terminals 1 and 3 May Be Connected for Parallel Operation at Full Rating
- 45 V Blocking Voltage
- Low Forward Voltage Drop
- Guard-ring for Stress Protection and High dv/dt Capability (> 10 V/ns)
- 175°C Operating Junction Temperature
- Pb-Free Package is Available\*

# **Mechanical Characteristics**

- Case: Epoxy, Molded
- Weight: 4.3 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

## **MAXIMUM RATINGS**

Rating	Symbol	Max	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	45	V
Average Rectified Forward Current (Rated V <sub>R</sub> , T <sub>C</sub> = 125°C) Per Diode Per Device	I <sub>F(AV)</sub>	30 60	А
	I <sub>FRM</sub>	60	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I <sub>FSM</sub>	500	Α
Peak Repetitive Reverse Current (2.0 μs, 1.0 kHz)	I <sub>RRM</sub>	2.0	Α
Storage Temperature Range	T <sub>stg</sub>	-65 to +175	°C
Operating Junction Temperature (Note 1)	TJ	-65 to +175	°C
Peak Surge Junction Temperature (Forward Current Applied)	T <sub>J(pk)</sub>	175	ç
Voltage Rate of Change	dv/dt	10,000	V/μs

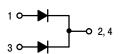
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

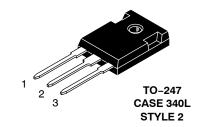


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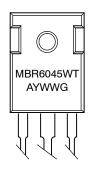
http://onsemi.com

# SCHOTTKY BARRIER RECTIFIER 60 AMPERES, 45 VOLTS





# **MARKING DIAGRAM**



A = Assembly Location

/ = Year

WW = Work Week
G = Pb-Free Package

### ORDERING INFORMATION

Device	Package	Shipping
MBR6045WT	TO-247	30 Units/Rail
MBR6045WTG	TO-247 (Pb-Free)	30 Units/Rail

<sup>1.</sup> The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **MBR6045WT**

# THERMAL CHARACTERISTICS (Per Diode)

Rating	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	1.0	°C/W
ELECTRICAL CHARACTERISTICS (Per Diode)			

Instantaneous Forward Voltage (Note 2)	$V_{F}$		Volts
@ $I_F = 30 \text{ Amps}, T_C = 25^{\circ}\text{C}$		0.62	
@ I <sub>F</sub> = 30 Amps, T <sub>C</sub> = 125°C		0.55	
@ I <sub>F</sub> = 60 Amps, T <sub>C</sub> = 25°C		0.75	
Instantaneous Reverse Current (Note 2)	I <sub>R</sub>		mA
@ Rated DC Voltage, T <sub>C</sub> = 25°C		1.0	
@ Rated DC Voltage, T <sub>C</sub> = 100°C		50	

<sup>2.</sup> Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle < 2.0%

# TYPICAL ELECTRICAL CHARACTERISTICS

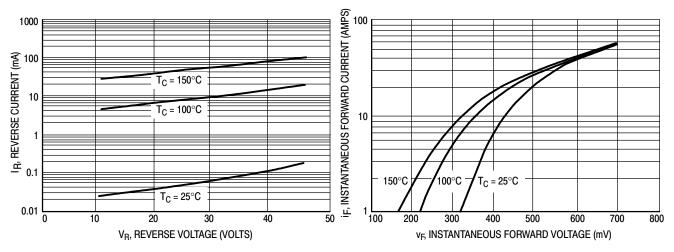


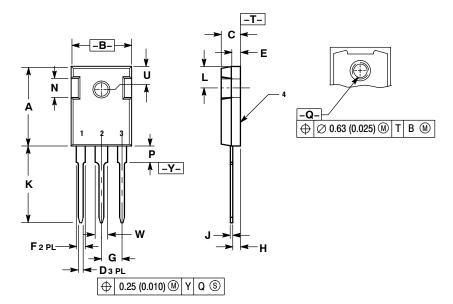
Figure 1. Typical Reverse Current

Figure 2. Typical Forward Voltage

# MBR6045WT

# PACKAGE DIMENSIONS

TO-247 CASE 340L-02 ISSUE E



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS IN		INC	NCHES	
DIM	MIN	MAX	MIN	MAX	
Α	20.32	21.08	0.800	8.30	
В	15.75	16.26	0.620	0.640	
c	4.70	5.30	0.185	0.209	
D	1.00	1.40	0.040	0.055	
Е	1.90	2.60	0.075	0.102	
F	1.65	2.13	0.065	0.084	
G	5.45	5.45 BSC		BSC	
Н	1.50	2.49	0.059	0.098	
7	0.40	0.80	0.016	0.031	
K	19.81	20.83	0.780	0.820	
L	5.40	6.20	0.212	0.244	
N	4.32	5.49	0.170	0.216	
Р		4.50		0.177	
Q	3.55	3.65	0.140	0.144	
U	6.15 BSC		0.242 BSC		
W	2.87	3.12	0.113	0.123	

- STYLE 2: PIN 1. ANODE
  - 2. CATHODE (S)
  - 3. ANODE 2
  - CATHODES (S)

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